# Possible High  $T_C$  Layered Ferromagnetic Insulator  $Sr_2NiRuO_4$ : An ab initio Study

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#### Abstract

Magnetic insulators are often antiferromagnetic (AFM) and layered AFM compounds usually show low ordering temperature. On the other hand, layered ferromagnetic (FM) insulators with high- $T_{\rm C}$  are very rare although they could be quite useful for spintronic applications. Here, using crystal field level analysis in combination with density functional theory calculations as well as Monte Carlo simulations, we predict that the layered insulator  $Sr_2NiRuO_4$  would have a strong FM coupling with  $T_{\rm C}$  as high as 240 K. The tetragonal crystal field in the Ni-O-Ru square plane stabilizes the  $S=1/2$  $Ni<sup>+</sup>$  and  $S=3/2$   $Ru<sup>3+</sup>$  states. The unique level ordering and occupation optimize the FM Ni-Ru superexchange interactions in the checkerboard arrangement, thus suggesting  $Sr_2NiRuO_4$  as an unusual high- $T_{\rm C}$  layered FM insulator. This work highlights the potential of charge-spin-orbital degrees of freedom for stabilizing strong FM coupling in layered oxides.

## 1 Introduction

Magnetic interactions between magnetic ions bonded by non-magnetic ligands arise via the superexchange mechanism first proposed by Anderson.<sup>[1](#page-13-0)</sup> A set of rules to predict the type of the interactions was proposed, independently, by Goodenough<sup>[2](#page-13-1)</sup> and Kanamori,<sup>[3](#page-13-2)</sup> and they have been rationalized as Goodenough-Kanamori-Anderson rules.<sup>[4](#page-13-3)</sup> Insulating transitionmetal oxides are often AFM due to the superexchange interactions. In correlated transitionmetal oxides, the strength of the coupling is given approximately by  $t^2/U$ , where t is an effective hopping parameter of the  $d$  electrons (hopping between two neighboring transition-metal sites) and U is the Coulomb interaction between two electrons on a same site.<sup>[4](#page-13-3)</sup> Among magnetic insulating oxides, the ferromagnetic (FM) ones are a minority and they are generally connected to orbital physics (*e.g.*, orbital ordering).<sup>[5](#page-14-0)-8</sup> The strength of the FM coupling is approximately given by  $t^2 J_H/U^2$  where  $J_H$  is the Hund coupling energy, and this contains a reduction factor  $J_H/U$  compared with the AFM case. Since the magnetic ordering tem-

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Figure 1: Crystal structure assumed by layered  $Sr_2NiRuO_4$  with the Ni-O-Ru square plane. perature is proportional to the exchange couplings, the FM insulators usually have a much lower ordering temperature than the AFM ones due the presence of  $J_H/U$  which is about

 $1/10 - 1/5.<sup>8</sup>$  $1/10 - 1/5.<sup>8</sup>$  $1/10 - 1/5.<sup>8</sup>$ 

Bulk FM insulators are interesting for spintronic applications since they could support proximity exchange fields in heterostructures and could provide spin-polarized carriers. $9-12$  $9-12$ However, a high- $T_{\rm C}$  FM insulator is rare due to the aforementioned weakened FM superexchange interactions, and this is even worse in two-dimensional FM materials. $9-11,13$  $9-11,13$  $9-11,13$ Transition-metal oxides are usually correlated electron systems which offer many multifunctional properties due to their lattice-charge-spin-orbital degrees of freedom and their cross-couplings.<sup>[5](#page-14-0)[–8](#page-14-1)[,14](#page-15-0)[,15](#page-15-1)</sup> These materials may host superconductivity, colossal magnetoresis-tance, and multiferroicity for example.<sup>[5](#page-14-0)[–8](#page-14-1)</sup> In this work, using a combination of crystal field level analyses, density functional calculations, and Monte Carlo simulations, we study the interplay among lattice-charge-spin-orbital degrees of freedoms and we predict a surprisingly strong FM layered insulator  $Sr_2NiRuO_4$  (see Fig. 1).

Recently, layered  $ABO<sub>2</sub>$  oxides were prepared via topochemical reduction from  $ABO<sub>3</sub>$ perovskites,[16](#page-15-2) and novel properties associated with this particular structure emerge. The representative SrFeO<sup>2</sup> has already attracted a lot of attention for its above room-temperature AFM order despite its layered structure.<sup>[16](#page-15-2)[,17](#page-15-3)</sup> It may undergo a spin crossover and a metal-insulator transition under pressure, thus forming an interesting FM half metallic state.<sup>[18](#page-15-4)</sup> Very recently, the Ni-Ru ordered  $\text{LaSrNiRuO}_4$  was synthesized and found to be a FM layered material with  $T_{\rm C} \sim 200$  K.<sup>[19](#page-15-5)</sup> The FM order has been explained by considering the superexchange between the unusual low-valence  $Ni^+$  and  $Ru^{2+}$  cations.<sup>[20](#page-15-6)</sup> The  $Ni^+$  (3 $d^9$ ) is in the  $S=1/2$  state and has an active  $x^2-y^2$  orbital under the influence of a square planar crystal field. The Ru<sup>2+</sup> ( $4d^6$ ) shows a  $S=1$  state stabilized by a moderate Hund exchange along with a weak crystal field.<sup>[20](#page-15-6)</sup> If the Ru<sup>2+</sup> ion were in the nonmagnetic  $S=0$  state as suggested in Ref.,<sup>[19](#page-15-5)</sup> the magnetic coupling would occur only in the diluted  $S=1/2$  Ni<sup>+</sup> sublattice, and it would thus be only weakly AFM due to a superexchange between the well separated Ni<sup>+</sup> ions with the half-filled  $x^2 - y^2$  orbital. Clearly, this would contradict the measured  $T_{\rm C} \sim$ 200 K. $^{19}$  $^{19}$  $^{19}$ 

Starting from these considerations, here we predict a surprisingly strong FM in the layered insulator  $\rm Sr_2NiRuO_4$ . This material would be very similar to the real LaSrNiRuO<sub>4</sub>,<sup>[19](#page-15-5)</sup> where half of the Sr atoms are substituted by La atoms. Its structural stability is confirmed by phonon calculations. The proposed  $Sr_2NiRuO_4$  compound should have a unique chargespin-orbital state such as  $S=1/2$  Ni<sup>+</sup> and  $S=3/2$  Ru<sup>3+</sup> in the tetragonal crystal field. Such a unique state favors an optimal and maximal superexchange interaction as confirmed by our density functional calculations, and in turn, yields  $T_{\rm C} > 240$  K as predicted by our Monte Carlo simulations. Therefore,  $Sr_2NiRuO_4$  would be an unusual high- $T_C$  layered FM insulator if synthesized.

## 2 Methods and computational details

We perform density functional theory (DFT) calculations using the Vienna Ab initio Sim-ulation Package (VASP).<sup>[21](#page-15-7)</sup> The phonon spectrum was calculated using phonopy software interfaced with VASP.<sup>[22](#page-15-8)</sup> The magnetic properties were studied using DFT, crystal field level diagram, as well as Monte Carlo simulations. We start our DFT calculations using the Local-Spin-Density Approximation (LSDA). The ionic potentials including the effect of core electrons are described by the projector augmented wave method.<sup>[23](#page-15-9)</sup> The plane waves with

the kinetic energy up to 500 eV have been employed to expand the electronic wave functions. A 16-atom unit cell of the Ni-Ru ordered  $Sr_2NiRuO_4$  (space group  $I4/mmm$ , see Fig. [1\)](#page-2-0) has been used to simulate the three magnetic structures studied below. The integration over the first Brillouin zone is carried out using Monkhorst-Pack grid of  $5 \times 5 \times 5$  *k*-point mesh. The structural relaxations are performed till the Hellmann-Feynman force on each atom is smaller than 0.01 eV/ $\AA$ . For the phonon calculations, the finite-displacements method is used, with the  $2 \times 2 \times 2$  supercell (128 atoms) and the  $3 \times 3 \times 2$  *k*-point mesh. To describe the onsite electron correlation and to estimate the magnetic exchange parameters, the LSDA plus Hubbard U (LSDA+U) method is employed,<sup>[24](#page-16-0)</sup> with the Coulomb and exchange parameters chosen to be the common values of  $U = 6$  eV (3 eV) and  $J = 1$  eV (0.6 eV) for Ni 3d (Ru 4d) electrons.<sup>[19](#page-15-5)</sup> Other reasonable values<sup>[14](#page-15-0)</sup> of U = 5 eV (2 eV) for Ni 3d (Ru 4d) are also considered in order to verify that our conclusions remain qualitatively unchanged. More-over, hybrid functional calculations using the Heyd-Scuseria-Ernzerhof (HSE) functional<sup>[25](#page-16-1)</sup> are carried out, and the obtained results further confirm our conclusions.

## 3 Results and discussion

#### 3.1 Phonon calculation

We have used the LSDA calculations to optimize the lattice parameters of  $Sr<sub>2</sub>NiRuO<sub>4</sub>$  in the I4/mmm structure. The obtained lattice constants are  $a=5.48$  Å and  $c=6.88$  Å, being well comparable with the experimental ones of  $a=5.66$  Å and  $c=6.90$  Å for the parent com-pound LaSrNiRuO<sub>4</sub>.<sup>[19](#page-15-5)</sup> To verify the structural stability of  $Sr_2NiRuO_4$ , we have performed the phonon calculations. The obtained phonon spectrum is shown in Fig. [2.](#page-5-0) There are no imaginary frequencies over the Brillouin zone, and thus  $Sr<sub>2</sub>NiRuO<sub>4</sub>$  would be dynamically stable in the I4/mmm structure. As shown below, this stable lattice structure can host a unique charge-spin-orbital state of the Ni and Ru atoms and it is free of a Jahn-Teller distortion.

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Figure 2: Calculated phonon spectrum of  $Sr_2NiRuO_4$ .

#### 3.2 LSDA calculations: charge-spin-orbital state and magnetism

We have studied, for the stable I4/mmm lattice, three different magnetic structures, *i.e.*, FM, A-AF(ab-intralayer FM, c-interlayer AFM) and C-AF (ab-intralayer AFM, c-interlayer FM). Our calculations show that the FM state is the most stable magnetic configuration while the C-AF state is unstable and converges to the metastable A-AF state, see Table [1.](#page-6-0) The absence of C-AF state implies that the intralayer AFM coupling is highly unfavorable, and in turn, the intralayer FM is more stable as found in FM and A-AF states. Both the FM and A-AF states have comparable local spin moments. The spin moment of about 0.8-0.9  $\mu_{\rm B}$ /Ni would suggest to a Ni<sup>+</sup> (3d<sup>9</sup>) S=1/2 state, and that of 1.6-1.7  $\mu_{\rm B}$ /Ru would suggest an intermediate-spin  $Ru^{3+}$  (4d<sup>5</sup>) S=3/2 state. The large reduction of Ru spin moment from the formal 3  $\mu_{\rm B}$  is due to a strong covalency of the expanded Ru 4d orbitals with the oxygen ligands. Note, however, that it is hard to reconcile these calculated spin moments with  $\mathrm{Ni^{2+}}$ (low-spin S=0 or high-spin S=1) and  $Ru^{3+}$  (either low-spin S=1/2 or high-spin S=5/2). In addition, the calculated total spin moment of 3.53  $\mu_{\rm B}/\text{fu}$  (formula unit) in the FM ground state, including the contributions from oxygens  $(0.18 \mu_B/O)$  and the interstitial regions, agrees with the Ni<sup>+</sup> S=1/2 and Ru<sup>3+</sup> S=3/2 state that has the ideal total spin moment of 4  $\mu_{\rm B}/\mathrm{fu}$ . This unusual low-valence state will be further verified below. Therefore, despite the similar structure between  $Sr_2NiRuO_4$  and  $LaSrNiRuO_4$ ,<sup>[19](#page-15-5)</sup> they seem to have quite different

<span id="page-6-0"></span>Table 1: Relative total energies  $\Delta E$  (meV/fu), total and local spin moments ( $\mu_B$ ) of the FM, A-AF, and C-AF states calculated by LSDA, LSDA+U, and the HSE hybrid functional.  $Sr_2NiRuO_4$  is in the Ni<sup>+</sup> S=1/2 and Ru<sup>3+</sup> S=3/2 coupled FM ground state. The fixed-spin-moment (FSM) calculations are also included for the total S=1 and S=0 states. U<sub>1</sub> refers to U = 6 eV (3 eV) for Ni 3d (Ru 4d) electrons,  $U_2$  stands for  $U = 5$  eV (2 eV) for Ni 3d (Ru 4d) electrons.

$Sr_2NiRuO_4$	State	ΔE	Total	Ni	Ru
<b>LSDA</b>	FM	$\theta$	3.53	0.90	1.74
	$A-AF$	18	0.00	0.82	1.65
	$C-AF$	$\rightarrow$ A – A F			
	$FSM S=1$	124	2	0.17	1.28
	$FSM S=0$	300	0	$\Omega$	0
$LSDA+U_1$	FM	0	4.00	1.13	2.09
	$A-AF$	20	0	1.14	2.06
	$C-AF$	162	0	0.74	1.95
$LSDA+U2$	FM	0	4.00	1.17	1.97
	$A-AF$	27	0	1.15	1.92
	$C-AF$	194	0	0.68	1.81
<b>HSE</b>	FM	0	4.00	1.13	2.16
	$A-AF$	24	0	1.12	2.15
	C-AF	299	0	0.76	2.05

electronic states. In particular, while for the latter the  $S=1/2$  Ni<sup>+</sup>/S=0 Ru<sup>2+</sup> state was suggested,<sup>[19](#page-15-5)</sup> for the former we propose the  $S=1/2$  Ni<sup>+</sup>/S=3/2 Ru<sup>3+</sup> state (but not the S=0  $Ni^{2+}/S=0$  Ru<sup>2+</sup> or  $S=0$  Ni<sup>2+</sup>/S=1 Ru<sup>2+</sup>, see more below). We will show that this unique charg-spin-orbital state is responsible for the enhancement of the FM couplings in  $Sr_2NiRuO_4$ as compared to the parent compound  $\text{LaSrNiRuO}_4$ .

We plot in Fig. [3](#page-7-0) the orbitally resolved density of states (DOS) for the FM ground state. For Ni 3d states,  $3z^2-r^2$  orbital lies at the lowest energy, which is followed by the degenerate  $xz/yz$ . The xy orbital can be found at higher energy and the  $x^2-y^2$  orbital highest. Except for the down-spin  $x^2-y^2$  state, all other Ni 3d states are (almost) fully occupied, thus suggesting the Ni<sup>+</sup> (3d<sup>9</sup>) S=1/2 state. As seen in Fig [3,](#page-7-0) Ru 4d states generally lie at higher energy than Ni 3d ones. This is in accordance with the chemical trend that Ru has a higher chemical potential (on site energy) than Fe (both elements in the same group) and Fe higher than the later transition metal Ni. In  $Sr_2NiRuO_4$ , Ru should have a higher valence state than

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Figure 3: (a) Ni 3d and (b) Ru 4d DOS of  $Sr_2NiRuO_4$  calculated by LSDA. The blue (red) curves stand for the up (down) spin channel. Fermi level is set at zero energy.

Ni, and the  $Ni^+$ -Ru<sup>3+</sup> charge state should be more stable than  $Ni^{2+}$ -Ru<sup>2+</sup> configuration, as seen below. The Ru 4d states have the same energy level sequence as the Ni 3d ones, but the crystal field splitting of the former is much bigger, as one can see from Fig. [3.](#page-7-0) In particular, Ru 4d  $x^2-y^2$  orbital has a large bonding-antibonding splitting of about 10 eV due to the significant Ru-O hybridization in the ab plane. As a result, the antibonding  $x^2-y^2$  state can be found at very high energy ( $> 2$  eV above Fermi level) and therefore it is completely unoccupied. In addition, the down-spin xy and xz/yz states are (almost) empty. This suggests that, besides the  $\mathrm{Ni^+}$  S=1/2 state in  $\mathrm{Sr_2NiRuO_4},$  Ru has an electronic configuration  $(3z^2-r^2)^2(xz)^1(yz)^1(xy)^1(x^2-y^2)^0$ , *i.e.*, the intermediate-spin Ru<sup>3+</sup>  $(4d^5, S=3/2)$ state. Note that both the  $Ni^+$  and  $Ru^{3+}$  ions are in an orbital singlet, and thus an insulating behavior of  $Sr_2NiRuO_4$  is expected. While the present LSDA calculations give a small DOS intensity at the Fermi level due to the tiny overlap between the up-spin  $Ni^+$   $x^2 - y^2$  and the down-spin Ru<sup>3+</sup>  $xz/yz$  bands (see Fig. 3), the insulating behavior is readily recovered by introducing a finite electron correlation as shown below.

We plot in Fig. [4](#page-8-0) a schematic level diagram for  $Ni^+$  S=1/2 and  $Ru^{3+}$  S=3/2 ground state as derived from the above LSDA calculations. We have also considered different charge-

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Figure 4: Schematic crystal field level diagrams of  $Ni^+ S = 1/2$  and  $Ru^{3+} S = 3/2$ . Virtual electron hoppings from  $Ni^+$  to  $Ru^{3+}$  favor FM superexchanges and thus optimize the FM Ni-Ru coupling via the four channels (the dashed curves).

spin states of  $Sr_2NiRuO_4$ , such as  $Ni^{2+} S=0$  and  $Ru^{2+} S=1$  (see Fig. [4,](#page-8-0) without  $Ni^{2+} x^2 - y^2$ electron and with  $Ru^{2+} (xz,yz)^3)$ , and  $Ni^{2+} S=0$  and  $Ru^{2+} S=0$  (with  $Ru^{2+} (3z^2-r^2)^2 (xz,yz)^4)$ . These configurations were stabilized using fixed-spin-moment calculations. This approach shows that the total S=1 state of  $Sr_2NiRuO_4$  mimics the Ni<sup>2+</sup> S=0 and Ru<sup>2+</sup> S=1 state and turns out to be less stable than the  $Ni^+ S=1/2$  and  $Ru^{3+} S=3/2$  ground state by 124 meV/fu (see Table [1\)](#page-6-0). Moreover, the total S=0 state (to mimic the  $Ni^{2+} S=0$  and  $Ru^{2+}$  $S=0$  state) is even higher in energy than the ground state by 300 meV/fu. Once again, these computational experiments confirm the Ni<sup>+</sup> S=1/2 and Ru<sup>3+</sup> S=3/2 ground state. Since this electronic state (see Fig. [4\)](#page-8-0) is an orbital singlet and it has no orbital degree of freedom, we suggest that  $Sr_2NiRuO_4$  can be stabilized in the  $I4/mmm$  structure (as verified by the above phonon calculations) which is free of a symmetry lowering Jahn-Teller lattice distortion. It is important to note that such unusual charge-spin-orbital states are crucial to produce the strong FM in this layered insulator, as discussed below.

#### 3.3 Ferromagnetic picture

Now we explain why  $Sr_2NiRuO_4$  should have a FM magnetic configuration with a high- $T_{\text{C}}$ , based on the crystal field pictures and inter-site orbital interactions. By considering virtual hopping processes, an electronic excitation from  $Ni^+$  to  $Ru^{3+}$  is possible which gives rise to an intermediate excited state  $Ni^{2+}/Ru^{2+}$ . Note that a reverse process would give the highly unbalanced  $\mathrm{Ni^0/Ru^{4+}}$  intermediate state and should be strongly suppressed. Therefore, we expect four channels associated with the charge excitation from  $Ni^+$ - $Ru^{3+}$  to  $Ni^{2+}$ - $Ru^{2+}$ , see Fig. [4.](#page-8-0) The spin-up  $x^2-y^2$  electron would yield a strong in-plane FM coupling via the significant pd $\sigma$  hybridizations of the Ni-O-Ru bonds. The spin-down xy electron would enhance the in-plane FM coupling via the relatively weaker  $p d \pi$  hybridizations (but with a smaller charge excitation gap of less than 1 eV, see Fig. [3\)](#page-7-0), and this is also the case for the down-spin xz/yz electrons. Moreover, the down-spin xz/yz electrons would yield a FM interlayer coupling via the  $d\sigma$  hybridizations (albeit there no bridging apical oxygens). Note that the particular Ni<sup>+</sup> S=1/2 and Ru<sup>3+</sup> S=3/2 state in the planar tetragonal crystal field is quite unique in producing the FM couplings via the inter-site orbital interactions. Except for the inactive  $3z^2-r^2$  orbital (doubly occupied due to the planar tetragonal crystal field), all the other four orbitals contribute to the FM coupling and therefore give rise to an optimal FM order.

### 3.4 LSDA+U and hybrid functional calculations

To support our picture, we have performed additional LSDA+U calculations to estimate the strength of both the intralayer and interlayer FM couplings in  $\rm Sr_2NiRuO_4$  in the stable  $\rm Ni^+$  $S=1/2$  and  $Ru^{3+} S=3/2$  state. As seen in Table [1,](#page-6-0) LSDA+U calculations account for the electron localization and stabilize the different magnetic structures for this layered insulator. Moreover, using constrained LSDA+U calculations,<sup>[14](#page-15-0)[,15](#page-15-1)</sup> we have tested the Ni<sup>2+</sup> S=0 and  $Ru^{2+} S=1$  state, and the Ni<sup>2+</sup> S=0 and  $Ru^{2+} S=0$  state. The former turns out to be unstable and converges exactly to the  $\mathrm{Ni^+}$  S=1/2 and  $\mathrm{Ru^{3+}}$  S=3/2 ground state. The latter is much higher in energy than the ground state by  $1550 \text{ meV/fu}$ . This confirms the above fixed-spinmoment calculations and both conclude the  $S=1/2$  Ni<sup>+</sup>/S=3/2 Ru<sup>3+</sup> ground state. The insulating electronic structure can be seen in Fig. [5,](#page-10-0) showing the orbitally resolved DOS results for the FM ground state given by LSDA+U. Again, the Ni<sup>+</sup> (S=1/2) and Ru<sup>3+</sup>

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Figure 5: (a) Ni 3d and (b) Ru 4d DOS of  $Sr_2NiRuO_4$  calculated by LSDA+U<sub>1</sub> (see also Table 1). The blue (red) curves stand for the up (down) spin channel. Fermi level is set at zero energy.

 $(S=3/2)$  ground state is verified, by counting the spin-orbital occupations of both Ni 3d and Ru 4d states. Therefore, our interpretation in terms of  $Ni^+$  (S=1/2) and  $Ru^{3+}$  (S=3/2) is robust with respect to different computational schemes.

By mapping the total energy differences between the FM ground state and the C-AF state, and A-AF states to a Heisenberg spin Hamiltonian (see Table [1\)](#page-6-0), the FM intralayer coupling parameter  $J_{ab}$  is estimated to be –27.0 meV  $(8J_{ab}S_{Ni}S_{Ru} = -162$  meV) and the FM interlayer one  $J_c = -6.7$  meV  $(4J_cS_{Ni}S_{Ru} = -20$  meV) when referring to the LSDA+U<sub>1</sub> scheme where  $U = 6$  eV  $(3 \text{ eV})$  could be an upper limit for Ni 3d (Ru 4d) electrons. When we refer to the LSDA+U<sub>2</sub> scheme with smaller  $U = 5$  eV (2 eV) for Ni 3d (Ru 4d) electrons, the FM exchange parameters get even bigger:  $J_{ab} = -32.3$  meV and  $J_c = -9.0$  meV. This is reasonable because by decreasing U parameter, the electron localization decreases and the energy separation between Ni 3d and Ru 4d states becomes smaller, thus favoring the virtual hoppings that we discussed before, and thus enhancing the FM couplings. Therefore, the estimated  $T_{\rm C}$  would be a minimum based on the LSDA+U<sub>1</sub> results. All these results show that indeed the intralayer FM coupling is significant and the interlayer one is also strong,

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Figure 6: Monte Carlo simulations of magnetization and magnetic susceptibility of  $Sr<sub>2</sub>NiRuO<sub>4</sub>$  as a function of temperature.  $T<sub>C</sub>$  is 240 K (blue curves) based on  $J<sub>ab</sub> = -27.0$ meV and  $J_c = -6.7$  meV, and  $T_c$  is 290 K (red curve) based on  $J_{ab} = -32.3$  meV and  $J_c =$ –9.0 meV.

thus confirming the above spin-orbital modeling analyses (Fig. [4\)](#page-8-0). As far as the local spin moments are concerned, with LSDA+U<sub>1</sub> (and LSDA+U<sub>2</sub>) values of about 1.1  $\mu_B/Ni^+$  and  $2.0~\mu_{\rm B}/{\rm Ru^{3+}}$  are larger than the corresponding LSDA ones, due to the electron localization introduced by the Hubbard U. The LSDA+U values and the calculated total spin moment of 4  $\mu_{\rm B}/{\rm fu}$  for the FM ground state clearly represent the unique Ni+ S=1/2 and Ru^3+ S=3/2 state.

Furthermore, hybrid functional HSE calculations are carried out, and they reach the same conclusion as the LSDA and LSDA+U calculations do, that is,  $Sr_2NiRuO_4$  is stabilized in the  $S=1/2$  Ni<sup>+</sup>/S=3/2 Ru<sup>3+</sup> ground state, see Table I. While the  $J_c$  value changes insignificantly by a comparison between the HSE and LSDA+ $U_1$  (and LSDA+ $U_2$ ) calculations of the FM and A-AF states, the  $J_{ab}$  value is nearly doubled when comparing the HSE and LSDA+U<sub>1</sub> calculations of the FM and C-AF states. Therefore, our HSE calculations would give a much higher  $T_{\rm C}$  than the LSDA+U<sub>1</sub> calculations do.

#### 3.5 Monte Carlo simulations: high  $T_{\rm C}$  layered ferromagnetism

Finally, we perform Monte Carlo simulations to confirm our prediction of a high  $T_{\rm C}$  for the layered insulator  $Sr_2NiRuO_4$ , using the stable  $Ni^+$   $S=1/2$  and  $Ru^{3+}$   $S=3/2$  states and the

above LSDA+ $U_1$  (and LSDA+ $U_2$ ) calculated FM Ni-Ru exchange parameters. We have used a three dimensional spin lattice and we assumed a Heisenberg spin Hamiltonian for the nearest neighboring Ni-Ru sites. Each spin is isotropic and can be rotated arbitrarily in three dimensional space, and the noncollinearity between the spins has been taken into account. The Metropolis method<sup>[26](#page-16-2)</sup> was used in the simulations. The system is fully relaxed by  $3\times10^7$  spin flips at each temperature. After the system reaches equilibrium at a given temperature, we calculate the magnetization M (the total magnetic moment of the system) and the magnetic susceptibility by  $\chi = (M^2 > - \langle M \rangle^2) / k_B T$ . M is sampled after each  $6 \times 10^3$ spin flips, and  $6\times10^3$  magnetizations are used to take the average. Based on the LSDA+U<sub>1</sub> FM exchange parameters  $J_{ab} = -27.0$  meV and  $J_c = -6.7$  meV, the simulation results are shown in Fig. [6](#page-11-0) (blue curves). The calculated magnetization and magnetic susceptibility show that the Curie temperature  $T_{\rm C}$  is 240 K, which may be a minimum but is already quite high for a layered insulator. Moreover, when we use  $J_{ab} = -32.3$  meV and  $J_c = -9.0$  meV from LSDA+U<sub>2</sub>,  $T_{\rm C}$  is increased up to 290 K, see the red curve in Fig. [6.](#page-11-0) In addition, as our HSE calculations give a nearly doubled  $J_{ab}$  value than the LSDA+U<sub>1</sub>, the corresponding  $T_{\rm C}$ should be significantly enhanced and then should be much higher than room temperature. Therefore, we have predicted an unusual strong FM in the layered insulator  $Sr_2NiRuO_4$ , whose  $T_{\rm C}$  is close to or ever higher than room temperature. This prediction of a high  $T_{\rm C}$  in the stable  $Sr_2NiRuO_4$  calls for an experimental proof.

## 4 Conclusion

In summary, we have predicted a surprising strong FM coupling in the stable layered insulator  $Sr<sub>2</sub>NiRuO<sub>4</sub>$ , using crystal field level analyses, density functional calculations for phonon and magnetism, and Monte Carlo simulations. Our results show that  $Sr<sub>2</sub>NiRuO<sub>4</sub>$  has the unique  $S=1/2$  Ni<sup>+</sup> and  $S=3/2$  Ru<sup>3+</sup> state in the planar tetragonal crystal field. The unique charge-spin-orbital states give rise to optimal FM couplings, which are confirmed by density functional calculations. Our Monte Carlo simulations show that  $Sr_2NiRuO_4$  should have a  $T_{\rm C}$  $> 240$  K thus representing a possible FM layered insulator with surprising high  $T_{\rm C}$ . This work highlights how unusual charge-spin-orbital states could stabilize strong FM interactions in novel layered oxide insulators. This certainly calls for further theoretical and experimental studies in this direction in order to design new layered FM materials suitable for device applications.

## Acknowledgement

H.W. conceived and supervised the research. K.Y. and F.-R.F. contributed equally to the work by carrying out the calculations with assistance from H.W. and A.S. All authors performed data analysis and co-wrote the manuscript. This work was supported by the NSF of China (Grants No. 11474059 and No. 11674064) and the National Key Research and Development Program of China (Grant No. 2016YFA0300700). F.-R. Fan was also partially supported by the Key Laboratory of Polar Materials and Devices (MOE), East China Normal University (Grant No. KFKT20160003).

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Figure 7: TOC Graphic